imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

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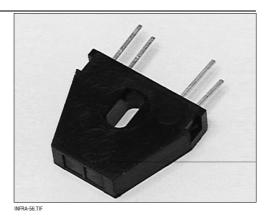


HOA0708/0709

Reflective Sensor

FEATURES

- Choice of phototransistor or photodarlington output
- Focused for maximum response
- · Ambient light and dust protective filter
- Adjustable mounting slot

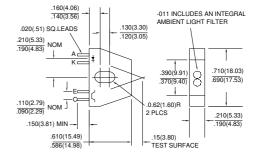


DESCRIPTION

The HOA0708/0709 series consists of an infrared emitting diode and an NPN silicon phototransistor (HOA0708-001, - 011) or photodarlington (HOA0709-001, - 011) encased side. by- side on converging optical axes in a black thermoplastic housing. The detector responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA0708-011 and HOA0709-011 employ an IR transmissive filter to minimize the effects of visible ambient light and provide a smooth optical face which prevents the accumulation of airborne contaminants in the optical path. The HOA0708/0709 series employs plastic molded components. For additional component information see SEP8505, SDP8405, and SDP8105.

Housing material is polycarbonate. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol. OUTLINE DIMENSIONS in inches (mm) Tolerance 3 plc decimals ±0.010(0.25)

2 plc decimals ±0.020(0.51)



DIM_033.ds4

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232

HOA0708/0709

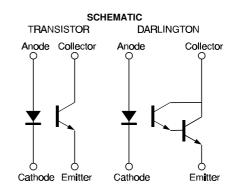
Reflective Sensor

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	l _F =20 mA
Reverse Leakage Current	IR			10	μA	V _R =3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	V(BR)CEO				V	Ic=100 μA
HOA0708-001, -011		30				
HOA0709-001, -011		15				
Emitter-Collector Breakdown Voltage	V(BR)ECO	5.0			V	I _E =100 μΑ
Collector Dark Current	ICEO				nA	V _{CE} =10 V
HOA0708-001, -011				100		IF=0
HOA0709-001, -011				250		
COUPLED CHARACTERISTICS						
On-State Collector Current	C(ON)					V _{CE} =5 V
HOA0708-001, -011		0.2				I⊧=40 mA
HOA0709-001, -011		1.0				(1)
Collector-Emitter Saturation Voltage	VCE(SAT)				V	I _F =40 mA ⁽¹⁾
HOA0708-001, -011				0.4		I _C =30 μΑ
HOA0709-001, -011				1.1		Ic=125 μΑ
Rise And Fall Time	t _r , t _f				μs	Vcc=5 V, Ic=1 mA
HOA0708-001, -011			15			RL=1000 Ω
HOA0709-001, -011			75			RL=100 Ω

Notes 1. Test surface is Eastman Kodak neutral white test card with 90% diffuse reflectance located 0.15 in. (3.80 mm) from the front surface of the device.

ABSOLUTE MAXIMUM RATINGS

Operating Temperature Range Storage Temperature Range	-40°C to 85° -40°C to 85°	0			
Soldering Temperature (5 sec)	240°C				
IR EMITTER					
Power Dissipation	70 mW ⁽¹⁾				
Reverse Voltage	3 V				
Continuous Forward Current	50 mA				
DETECTOR	TRANS.	DARLINGTON			
Collector-Emitter Voltage	30 V	15 V			
Emitter-Collector Voltage	5 V	5 V			
Power Dissipation	70 mW ⁽¹⁾	70 mW (1)			
Collector DC Current	30 mA	30 mA			



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HOA0708/0709 Reflective Sensor

Fig. 1 **IRED** Forward Bias Characteristics Fig. 2 Non-Saturated Switching Time vs gra_073.ds4 Load Resistance gra_079.ds4 1000 100 重量増度 畫 Ŧ 90 王日田臣 ヨ ∃|∓ ⊞|⊞ **4**|፹ Forward current - mA Pulsed Response time - µs 80 condition <u>-</u>111111 70 100 ≢≡⊨≡≡≣≣ Ŧ 国用 = 80°C 60 \square Photodarlington \square \square \square 50 + +-+++ 40 C 10 国田 ≣ 30 Ŧ 티파파 20 -40°C Phototransistor 10 ŦI++II+ + ++1+1 0 1 -10 100 1000 10000 1.0 1.2 1.6 1.8 2.0 0.8 1.4 Forward voltage - V Load resistance - Ohms Fig. 3 Dark Current vs Fig. 4 Collector Current vs gra_301.cdr Temperature Ambient Temperature gra_076.ds4 1000 1.2 Normalized collector current 1.0 VCE = 15 V 100 Dark current - nA H = 00.8 10 0.6 1 0.4 0.2 0.1 0.0 0.01 75 -25 ò 25 50 -50 100 -40 -20 ó 20 40 60 ВÒ 100 Free-air temperature - °C Free-air temperature - °C Fig. 5 Collector Current vs Fig. 6 Collector Current vs Distance to Reflective Surface **IRED** Forward Current gra_081.ds4 gra_080.ds4 1.0 1.4 Normalized collector current Normalized collector current 0.9 1.2 0.8 1.0 0.7 0.6 0.8 0.5 40 mA 0.6 0.4 $V_{CE} = 5V$ = 5.0 0.3 0.4 d = 0.15 in. 0.2 0.2 0.1 0.0 0.0 -0.00 0.05 0.10 0.15 0.20 0.25 0.30 ò 10 20 30 40 50 Distance to reflective surface - inches IRED forward current - mA

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234

All Performance Curves Show Typical Values



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